# S-L2985 Series

# HIGH RIPPLE-REJECTION WLP PACKAGE LOW DROPOUT CMOS VOLTAGE REGULATOR

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Rev.3.0\_00

The S-L2985 Series is a positive voltage regulator with a low dropout voltage, high output voltage accuracy, and low current consumption developed based on CMOS technology.

A built-in low on-resistance transistor provides a low dropout voltage and large output current, and a builtin overcurrent protector prevents the load current from exceeding the current capacitance of the output transistor. An ON/OFF circuit ensures a long battery life. Compared with the voltage regulators using the conventional CMOS process, a larger variety of capacitors are available, including small ceramic capacitors. A super-small WLP-4B package realizes high-density mounting.

# Features

<ul> <li>Output voltage:</li> </ul>	1.5 V to 5.5 V, selectable in 0.1 V steps.
<ul> <li>High-accuracy output voltage:</li> </ul>	±1.0%
<ul> <li>Low dropout voltage:</li> </ul>	190 mV typ. (3.0 V output product, l <sub>out</sub> = 100 mA)
<ul> <li>Low current consumption:</li> </ul>	During operation: 50 μA typ., 90 μA max.
	During shutdown: 0.1 μA typ., 1.0 μA max.
<ul> <li>High peak current capability:</li> </ul>	150 mA output is possible (@V <sub>IN</sub> ≥V <sub>OUT(S)</sub> + 1.0 V) <sup>*1</sup>
<ul> <li>Built-in ON/OFF circuit:</li> </ul>	Ensures long battery life.
• Low ESR capacitor can be used:	A ceramic capacitor of 0.47 $\mu$ F or more can be used for the output
	capacitor.
<ul> <li>High ripple rejection:</li> </ul>	80 dB typ. (@1.0 kHz)
Built-in overcurrent protector:	Overcurrent of output transistor can be restricted.
<ul> <li>Lead-free, halogen-free</li> </ul>	

\*1. Attention should be paid to the power dissipation of the package when the output current is large.

# Applications

- Power supply for battery-powered devices
- Power supply for personal communication devices
- Power supply for home electric/electronic appliances
- Power supply for cellular phones

# Package

• WLP-4B

# HIGH RIPPLE-REJECTION WLP PACKAGE LOW DROPOUT CMOS VOLTAGE REGULATOR S-L2985 Series Rev.3.0\_00

## Block Diagram



## Product Code Structure

• The product types, output voltage and package name for the S-L2985 Series can be selected at the user's request. Refer to the "1. Product Name" for the construction of the product name, "2. Package" regarding the package drawings and "3. Product Name List" for the full product names.

#### 1. Product name



- \*1. Refer to the tape specifications at the end of this book.
- \*2. Refer to 3. Shutdown (ON/OFF pin) under the Operation.

#### 2. Package

Package name		Drawing code	
Package name	Package	Tape	Reel
WLP-4B	HB004-A-P-SD	HB004-A-C-SD	HB004-A-R-SD

#### 3. Product name list

Table 1						
Output voltage	WLP-4B					
1.5V±1.0%	S-L2985B15-H4T1					
1.8V±1.0%	S-L2985B18-H4T1					
2.5V±1.0%	S-L2985B25-H4T1					
2.6V±1.0%	S-L2985B26-H4T1					
2.7V±1.0%	S-L2985B27-H4T1					
2.8V±1.0%	S-L2985B28-H4T1					
2.9V±1.0%	S-L2985B29-H4T1					
3.0V±1.0%	S-L2985B30-H4T1					
3.1V±1.0%	S-L2985B31-H4T1					
3.2V±1.0%	S-L2985B32-H4T1					
3.3V±1.0%	S-L2985B33-H4T1					
3.4V±1.0%	S-L2985B34-H4T1					
3.5V±1.0%	S-L2985B35-H4T1					
5.0V±1.0%	S-L2985B50-H4T1					

**Remark** Please contact the SII marketing department for products with an output voltage other than those specified above or type A products.

# ■ Pin Configuration

WLP-4B		Tab	le 2
Top view	Pin No.	Symbol	Description
$ \begin{bmatrix} 1 & 4 \\ \bigcirc & \bigcirc \end{bmatrix} $	1	VSS	GND pin
$ \bigcirc \bigcirc $	2	VOUT	Output voltage pin
	3	VIN	Input voltage pin
2 3	4	ON/OFF	Shutdown pin
Figure 2			

# Absolute Maximum Ratings

#### Table 3

	$(Ta = 25^{\circ}C \text{ unless otherwise specified})$					
Item	Symbol	Absolute Maximum Rating	Unit			
Input voltage	V <sub>IN</sub>	$V_{SS}$ – 0.3 to $V_{SS}$ + 7	V			
	V <sub>ON/OFF</sub>	$V_{SS}$ – 0.3 to $V_{IN}$ + 0.3				
Output voltage	V <sub>OUT</sub>	$V_{SS}$ – 0.3 to $V_{IN}$ + 0.3				
Power dissipation	P <sub>D</sub>	350*1	mW			
Operating ambient temperature	T <sub>opr</sub>	-40 to +85	O°			
Storage temperature	T <sub>stg</sub>	-40 to +125				

\*1. When mounted on board

[Mounted board]

(1) Board size :  $114.3 \text{ mm} \times 76.2 \text{ mm} \times t1.6 \text{ mm}$ 

(2) Board name : JEDEC STANDARD51-7

# Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.





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# Electrical Characteristics

Table 4

(Ta = 2					°C unles	s otherv	vise sp	ecified)
Item	Symbol	Conditions		Min.	Тур.	Max.	Unit	Test Circuit
Output voltage <sup>*1</sup>	V <sub>OUT(E)</sub>	$V_{IN} {=} V_{OUT(S)} {+} 1.0 \ V, \ I_{OUT} {=}$	30 mA	$\begin{array}{c} V_{OUT(S)} \\ \times \ 0.99 \end{array}$	V <sub>OUT(S)</sub>	$V_{OUT(S)} \times 1.01$	V	1
Output current <sup>*2</sup>	Ι <sub>ουτ</sub>	$V_{IN} \ge V_{OUT(S)} + 1.0 V$		150 <sup>*5</sup>			mA	3
Dropout voltage <sup>*3</sup>	V <sub>drop</sub>	$I_{OUT} = 100 \text{ mA}$ $1.5 \text{ V} \le \text{V}$	$V_{OUT(S)} \le 1.6 \text{ V}$	—	0.32	0.55	V	1
		1.7 V ≤ V	$V_{OUT(S)} \le 1.8 \text{ V}$		0.28	0.47		
		1.9 V ≤ V	$V_{OUT(S)} \le 2.3 \text{ V}$		0.25	0.35		
		$2.4 \text{ V} \leq \text{V}$	$V_{OUT(S)} \le 2.7 \text{ V}$	_	0.20	0.29		
		$2.8 \text{ V} \leq \text{V}$	$V_{OUT(S)} \leq 5.5 \text{ V}$		0.19	0.26		
Line regulation	$\Delta VOUT1$	$V_{OUT(S)} + 0.5 \ V \leq V_{IN} \leq 6.5 \ V, \label{eq:VOUT}$			0.05	0.2	%/V	
	$\Delta V {\sf IN} \bullet V {\sf O} {\sf U} {\sf T}$	$I_{OUT} = 30 \text{ mA}$			0.05	0.2	70 / V	
Load regulation	$\Delta V_{OUT2}$	$\label{eq:VIN} \begin{split} V_{IN} &= V_{OUT(S)} + 1.0 \ V, \\ 1.0 \ mA &\leq I_{OUT} \leq 80 \ mA \end{split}$		_	12	40	mV	
Output voltage	$\Delta V$ out	$V_{IN} = V_{OUT(S)} + 1.0 \text{ V}, I_{OUT} = 10 \text{ mA},$			±100		ppm	
temperature coefficient*4	<b>∆Ta</b> •Voυτ	$-40^{\circ}C \le Ta \le 85^{\circ}C$			±100		/ °C	
Current consumption during operation	I <sub>SS1</sub>	$V_{IN} = V_{OUT(S)} + 1.0 V$ , ON/OFF pin = ON, no load		_	50	90	μΑ	2
Current consumption during shutdown	I <sub>SS2</sub>	$V_{IN} = V_{OUT(S)} + 1.0 V$ , ON/OFF pin – OFF, no load		_	0.1	1.0		
Input voltage	V <sub>IN</sub>			2.0		6.5	V	
Shutdown pin input voltage "H"	V <sub>SH</sub>	$V_{IN} = V_{OUT(S)} + 1.0 V, R_L = 1.$	0 kΩ	1.5		_		4
Shutdown pin input voltage "L"	V <sub>SL</sub>	$V_{IN} = V_{OUT(S)} + 1.0 \text{ V}, \text{ R}_{L} = 1.0 \text{ k}\Omega$				0.3		
Shutdown pin input current "H"	I <sub>SH</sub>	V <sub>IN</sub> = 6.5 V, V <sub>ON/OFF</sub> = 6.5 V		-0.1	_	0.1	μA	
Shutdown pin input current "L"	I <sub>SL</sub>	$V_{IN} = 6.5 V, V_{ON/OFF} = 0 V$		-0.1		0.1		
Ripple rejection	RR	$V_{IN} = V_{OUT(S)} + 1.0 V$ , f = 1.0 kHz, $\Delta V_{rip} = 0.5 Vrms$ , $I_{OUT} = 30 mA$			80		dB	5
Short-circuit current	I <sub>short</sub>	$V_{IN} = V_{OUT(S)} + 1.0 \text{ V}, \text{ ON/OF}$ $V_{OUT} = 0 \text{ V}$	F pin = ON,		200		mA	3

\*1. V<sub>OUT(S)</sub>: Specified output voltage

V<sub>OUT(E)</sub>: Actual output voltage at the fixed load

The output voltage when fixing  $I_{OUT}$  (= 30 mA) and inputting  $V_{OUT(S)}$  + 1.0 V

\*2. The output current at which the output voltage becomes 95% of V<sub>OUT(E)</sub> after gradually increasing the output current.

**\*3.**  $V_{drop} = V_{IN1} - (V_{OUT3} \times 0.98)$ 

 $V_{OUT3}$  is the output voltage when  $V_{IN} = V_{OUT(S)} + 1.0$  V and  $I_{OUT} = 100$  mA.

 $V_{IN1}$  is the input voltage at which the output voltage becomes 98% of  $V_{OUT3}$  after gradually decreasing the input voltage. \*4. The change in temperature [mV/°C] is calculated using the following equation.

$$\frac{\Delta V_{\text{out}}}{\Delta Ta} \left[ mV/^{\circ}C \right]^{*1} = V_{\text{out(s)}} \left[ V \right]^{*2} \times \frac{\Delta V_{\text{out}}}{\Delta Ta \bullet V_{\text{out}}} \left[ ppm/^{\circ}C \right]^{*3} \div 1000$$

- \*1. The change in temperature of the output voltage
- \*2. Specified output voltage
- \*3. Output voltage temperature coefficient
- \*5. The output current can be at least this value.

Due to restrictions on the package power dissipation, this value may not be satisfied. Attention should be paid to the power dissipation of the package when the output current is large.

# Test Circuits



Figure 8

# Standard Circuit



- \*1.  $C_{IN}$  is a capacitor for stabilizing the input.
- \*2. A ceramic capacitor of 0.47  $\mu$ F or more can be used for C<sub>L</sub>.

#### Figure 9

Caution The above connection diagram and constant will not guarantee successful operation. Perform thorough evaluation using the actual application to set the constant.

## Application Conditions

Input capacitor ( $C_{IN}$ ): Output capacitor ( $C_L$ ): ESR of output capacitor: 1.0  $\mu$ F or more 0.47  $\mu$ F or more 10  $\Omega$  or less

Caution A general series regulator may oscillate, depending on the external components selected. Check that no oscillation occurs with the application using the above capacitor.

# Explanation of Terms

#### 1. Low dropout voltage regulator

The low dropout voltage regulator is a voltage regulator whose dropout voltage is low due to its built-in low on-resistance transistor.

#### 2. Low ESR

A capacitor whose ESR (Equivalent Series Resistance) is low. The S-L2985 Series enables use of a low ESR capacitor, such as a ceramic capacitor, for the output-side capacitor  $C_L$ . A capacitor whose ESR is 10  $\Omega$  or less can be used.

#### 3. Output voltage (V<sub>OUT</sub>)

The accuracy of the output voltage is ensured at  $\pm 1.0\%$  under the specified conditions of fixed input voltage<sup>\*1</sup>, fixed output current, and fixed temperature.

**\*1.** Differs depending on the product.

# Caution If the above conditions change, the output voltage value may vary and exceed the accuracy range of the output voltage. Please see the electrical characteristics and attached characteristics data for details.

# 4. Line regulation $\left(\frac{\Delta V_{OUT1}}{\Delta V_{IN} \bullet V_{OUT}}\right)$

Indicates the dependency of the output voltage on the input voltage. That is, the values show how much the output voltage changes due to a change in the input voltage with the output current remaining unchanged.

#### 5. Load regulation ( $\Delta V_{OUT2}$ )

Indicates the dependency of the output voltage on the output current. That is, the values show how much the output voltage changes due to a change in the output current with the input voltage remaining unchanged.

#### 6. Dropout voltage (V<sub>drop</sub>)

Indicates the difference between the input voltage  $V_{IN1}$ , which is the input voltage  $(V_{IN})$  at the point where the output voltage has fallen to 98% of the output voltage value  $V_{OUT3}$  after  $V_{IN}$  was gradually decreased from  $V_{IN} = V_{OUT(S)} + 1.0$  V, and the output voltage at that point ( $V_{OUT3} \times 0.98$ ).

$$V_{drop} = V_{IN1} - (V_{OUT3} \times 0.98)$$

# 7. Temperature coefficient of output voltage $\left(\frac{\Delta V_{OUT}}{\Delta Ta \bullet V_{OUT}}\right)$

The shadowed area in **Figure 10** is the range where  $V_{OUT}$  varies in the operating temperature range when the temperature coefficient of the output voltage is ±100 ppm/°C.



\*1.  $V_{OUT(E)}$  is the value of the output voltage measured at 25°C.

# Figure 10

A change in the temperature of the output voltage [mV/°C] is calculated using the following equation.

- $\frac{\Delta V_{\text{out}}}{\Delta Ta} \left[ mV/^{\circ}C \right]^{*1} = V_{\text{out(s)}} \left[ V \right]^{*2} \times \frac{\Delta V_{\text{out}}}{\Delta Ta \bullet V_{\text{out}}} \left[ ppm/^{\circ}C \right]^{*3} \div 1000'$
- \*1. Change in temperature of output voltage
- \*2. Specified output voltage
- \*3. Output voltage temperature coefficient

# Operation

#### 1. Basic operation

Figure 11 shows the block diagram of the S-L2985 Series.

The error amplifier compares the reference voltage ( $V_{ref}$ ) with  $V_{fb}$ , which is the output voltage resistancedivided by feedback resistors  $R_s$  and  $R_f$ . It supplies the output transistor with the gate voltage necessary to ensure a certain output voltage free of any fluctuations of input voltage and temperature.



#### 2. Output transistor

The S-L2985 Series uses a low on-resistance P-channel MOS FET as the output transistor. Be sure that  $V_{OUT}$  does not exceed  $V_{IN}$  + 0.3 V to prevent the voltage regulator from being damaged due to inverse current flowing from the VOUT pin through a parasitic diode to the VIN pin.

#### 3. Shutdown pin (ON/OFF pin)

This pin starts and stops the regulator.

When the ON/OFF pin is set to the shutdown level, the operation of all internal circuits stops, and the builtin P-channel MOS FET output transistor between the VIN pin and VOUT pin is turned off to substantially reduce the current consumption. The VOUT pin becomes the V<sub>SS</sub> level due to the internally divided resistance of several M $\Omega$  between the VOUT pin and VSS pin.

The structure of the ON/OFF pin is as shown in **Figure 12**. Since the ON/OFF pin is neither pulled down nor pulled up internally, do not use it in the floating state. In addition, note that the current consumption increases if a voltage of 0.3 V to  $V_{IN} - 0.3$  V is applied to the ON/OFF pin. When the ON/OFF pin is not used, connect it to the VSS pin if the logic type is "A" and to the VIN pin if it is "B".

-	[	[		
Logic Type	ON/OFF Pin	Internal Circuits	VOUT Pin Voltage	Current Consumption
А	"L": Power on	Operating	Set value	I <sub>SS1</sub>
А	"H": Power off	Stopped	V <sub>SS</sub> level	I <sub>SS2</sub>
В	"L": Power off	Stopped	V <sub>ss</sub> level	I <sub>SS2</sub>
В	"H": Power on	Operating	Set value	I <sub>SS1</sub>





# ■ Selection of Output Capacitor (C<sub>L</sub>)

The S-L2985 Series requires an output capacitor between the VOUT and VSS pins for phase compensation. A ceramic capacitor with a capacitance of 0.47  $\mu$ F or more can be used. Even if using an OS capacitor, tantalum capacitor, or aluminum electrolytic capacitor, a capacitance of 0.47  $\mu$ F or more and an ESR of 10  $\Omega$  or less are required.

The value of the output overshoot or undershoot transient response varies depending on the value of the output capacitor.

When selecting the output capacitor, perform sufficient evaluation, including evaluation of temperature characteristics, on the actual device.

# Precautions

- Wiring patterns for the VIN, VOUT and GND pins should be designed so that the impedance is low. When mounting an output capacitor( $C_L$ ) or an input capacitor( $C_{IN}$ ), the distance from the capacitor to the VOUT pin and to the VSS pin should be as short as possible.
- Note that the output voltage may increase when a series regulator is used at low load current (1.0 mA or less).
- Generally a series regulator may cause oscillation, depending on the selection of external parts. The following conditions are recommended for this IC. However, be sure to perform sufficient evaluation including the temperature characteristic in the actual usage conditions to select the series regulator.

- The voltage regulator may oscillate when the impedance of the power supply is high and the input capacitor is small or an input capacitor is not connected.
- The application conditions for the input voltage, output voltage, and load current should not exceed the package power dissipation.
- The side of device silicon substrate is exposed to the marking side of device package. Since this portion has lower strength against the mechanical stress than the standard plastic package, be careful of the handing of a package enough against chip, crack etc. Moreover, the exposed side of silicon has electrical potential of device substrate, and needs to be kept out of contact with the external potential.
- In this package, the overcoat of the resin of translucence is carried out on the side of device. Keep it mind that it may affect the characteristic of a device when exposed a device in the bottom of a high light source.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- In determining the output current, attention should be paid to the output current value specified in Table 4 in the electrical characteristics and footnote \*5) of the table.
- SII claims no responsibility for any disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

# Precautions for WLP package

- The side of device silicon substrate is exposed to the marking side of device package. Since this portion has lower strength against the mechanical stress than the standard plastic package, chip, crack, etc should be careful of the handing of a package enough. Moreover, the exposed side of silicon has electrical potential of device substrate, and needs to be kept out of contact with the external potential.
- In this package, the overcoat of the resin of translucence is carried out on the side of device area. Keep it mind that it may affect the characteristic of a device when exposed a device in the bottom of a high light source.

# Typical Characteristics

#### (1) Output Voltage vs. Output current (when load current increases)

S-L2985B15 (Ta = 25°C) S-L2985B30 (Ta = 25°C) 1.8 3.5 1.6 3.0 1.4 2.5 1.2 6.5 V  $V_{IN} = 3.3 V$ 2.0 1.0 Vour [V]  $V_{IN} = 1.8 V^{2}$ Vout [V] 6.5 V 0.8 1.5 0.6 1.0 0.4 2.5 V 4.0 \ 0.5 0.2 0,0 0 100 200 300 400 500 600 0 100 200 300 400 500 600 IOUT [mA] IOUT [mA] S-L2985B50 (Ta = 25°C) 6 5 4  $V_{IN} = 5.3 V^{-1}$ Vour [V] 3 **Remark** In determining the output current, attention 6.0 V <sup>,</sup> 2 should be paid to the following. 6.5 V The minimum output current value 1) 1 and footnote \*5 in the electrical 0 characteristics 0 100 200 300 400 500 600 2) The package power dissipation IOUT [mA] (2) Output voltage vs. Input voltage S-L2985B15 (Ta = 25°C) S-L2985B30 (Ta = 25°C) 1.6 3.1 1.5 3.0 1.4 2.9 Vour [V] Vour [V] <sub>OUT</sub> = 1 mA 1.3 2.8  $I_{OUT} = 1 \text{ mA}$ -30 mA 30 mA 1.2 2.7 50 mA 50 mA 1.1 2.6 2.5 2.5 1.0 1.5 2.0 2.5 3.0 3.5 3.0 3.5 4.0 4.5 5.0 1.0 VIN [V] VIN [V] S-L2985B50 (Ta = 25°C) 5.5 5.0 4.5 Vout [V]  $I_{OUT} = 1 \text{ mA}$ 4.0 50 mA 3.5 .30 mA 3.0 2.5 **-**2.0 7.0 3.0 4.0 5.0 6.0 VIN [V]

#### (3) Dropout voltage vs. Output current



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S-L2985B30 1.60 3.20 3.15 3.10 1.55 3.05 Vout [V] Vout [V] 1.50 3.00 2.95 1.45 2.90 2.85 1.40 2.80 -25 50 -50 -25 0 25 50 75 100 -50 0 25 75 100 Ta [°C] Ta [°C] S-L2985B50 5.3 5.2 5.1 Vout [V] 5.0 4.9 4.8 4.7 -50 -25 0 25 50 75 100 Ta [°C] (6) Current consumption vs. Input voltage S-L2985B15 S-L2985B30 120 120 100 100 25°C -85°C 80 80 lssı [µA] lssı [µA] 25°C -40°C 60 60 -85°C 40 40 -40°C 20 20 0 0 2 2 6 8 0 4 6 0 4 VIN [V] VIN [V]

## (5) Output voltage vs. Ambient temperature

S-L2985B15





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# (7) Ripple rejection



Vin []

Vin [V

lour [mA]

# Reference Data

#### (1) Input transient response characteristics

S-L2985B15 (Ta = 25°C)

lout = 30 mA, tr = tf = 5.0  $\mu$ s, Cout = 0.47  $\mu$ F, Cin = 0  $\mu$ F





 $I_{OUT} = 30 \text{ mA}, \text{ tr} = \text{tf} = 5.0 \text{ } \mu\text{s}, \text{ C}_{OUT} = 0.47 \text{ } \mu\text{F}, \text{ C}_{IN} = 0 \text{ } \mu\text{F}$ 



t [µs]

#### (2) Load transient response characteristics

S-L2985B15 (Ta = 25°C)

 $V_{IN} = 2.5 V$ ,  $C_{OUT} = 0.47 \mu F$ ,  $C_{IN} = 1.0 \mu F$ ,  $I_{OUT} = 50 \leftrightarrow 100 \text{ mA}$ 



S-L2985B50 (Ta = 25°C)

 $V_{\text{IN}} = 6.0 \text{ V}, \text{ C}_{\text{OUT}} = 0.47 \text{ }\mu\text{F}, \text{ C}_{\text{IN}} = 1.0 \text{ }\mu\text{F}, \text{ I}_{\text{OUT}} = 50 {\leftrightarrow} 100 \text{ }\text{mA}$ 



3.08 6 5 3.06 Vin 4 3.04 Vout [V] 3 3.02 Vout 3.00 2 1 2.98 2.96 \_40 80 100 120 140 160 20 40 60 -20 0 t [µS]

IOUT = 30 mA, tr = tf = 5.0  $\mu$ s, Cout = 0.47  $\mu$ F, Cin = 0  $\mu$ F

S-L2985B30 (Ta = 25°C)



S-L2985B30 (Ta = 25°C)

 $V_{IN} = 4.0 \text{ V}, \text{ Cout} = 0.47 \text{ }\mu\text{F}, \text{ C}_{IN} = 1.0 \text{ }\mu\text{F}, \text{ lout} = 50 \leftrightarrow 100 \text{ mA}$ 



lou⊤ [mA]

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### (3) ON/OFF pin transient response characteristics









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